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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yamaguchi et al. Docket No: TI-31471
Serial No: TBD Examiner: TBD
Filed: Herewith Art Unit: TBD
For: SEMICONDUCTOR DEVICE AND BUMP FORMATION METHOD

CLAIM FOR PRIORITY FROM FOREIGN APPLICATION UNDER 35 U.S.C. §119

Assistant Commissioner For Patents
Washington, DC 20231

Dear Sir:

I hereby claim foreign priority benefits under 35 U.S.C. §119(a)-(d) or (f), or 365(b) of any foreign application(s) for patent, inventor's or plant breeder's rights certificate(s), or 365(a) of any PCT International application which designated at least one country other than the United States of America, listed below and have also identified below, by checking the box, any foreign application for patent, inventor's or plant breeder's rights certificate(s), or any PCT international application having a filing date before that of the application which priority is claimed.

Prior Foreign Application Number(s)	Country	Foreign Filing Date	Priority Not Claimed	Certified Copy Attached?
2001-061,381	Japan	03/06/2001	<input type="checkbox"/>	<input type="checkbox"/> <input checked="" type="checkbox"/>

Respectfully submitted,



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